NSN 5961-00-814-0319

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View Online at https://aerobasegroup.com/nsn/5961-00-814-0319 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Overall Diameter:** 0.650 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 28.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 3.50 amperes source cutoff current **Power Rating Per Characteristic:** 2.2 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 95.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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